



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

July 9, 2026

IGI Report Number

LG816653517

Description

LABORATORY GROWN DIAMOND

Shape and Cutting Style

CUSHION MODIFIED BRILLIANT

Measurements

9.75 X 7.48 X 5.13 MM

GRADING RESULTS

Carat Weight

3.06 CARATS

Color Grade

E

Clarity Grade

VVS 2

ADDITIONAL GRADING INFORMATION

Polish

EXCELLENT

Symmetry

EXCELLENT

Fluorescence

NONE

Inscription(s)

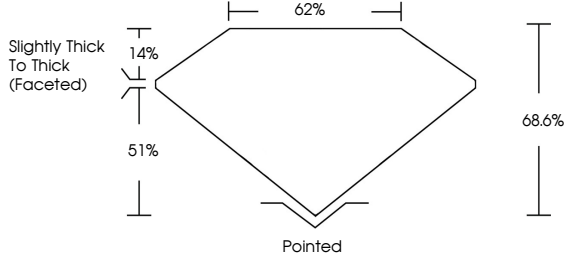
 LG816653517

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa

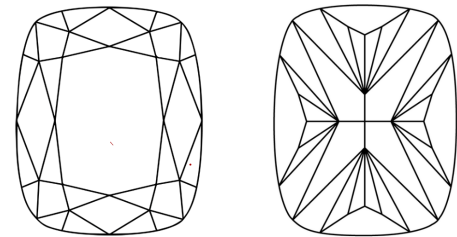
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Report verification at [igi.org](https://www.igi.org)

PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.



Sample Image Used

COLOR

D	E	F	G	H	I	J	Faint	Very Light	Light
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CLARITY

FL	IF	VVS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

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CUSHION MODIFIED BRILLIANT

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E

VVS 2

68.6%

62%

Slightly Thick To Thick (Faceted)

Pointed

EXCELLENT

EXCELLENT

NONE

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IGI



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